GS5802 High Efficiency 1.2MHz 2A Step Up Converter

Product Description

The GS5802 is a constant frequency, 6-pin SOT23-6L current mode step-up converter intended for small, low power applications.

The GS5802 switches at 1.2MHz and allows the use of tiny, low cost capacitors and inductors 2mm or less in height. Internal soft-start results in small inrush current and extends battery life.

The GS5802 features automatic shifting to pulse frequency modulation mode at light loads.

The GS5802 includes under-voltage lockout, current limiting, and thermal overload protection to prevent damage in the event of an output overload.

The GS5802 is available in a small 6-pin SOT-23-6L package.

Features

- Integrated 80mΩ Power MOSFET
- 2.3V to 24V Input Voltage
- 1.2MHz Fixed Switching Frequency
- Internal 4A Switch Current Limit
- Adjustable Output Voltage
- Internal Compensation
- Up to 28V Output Voltage
- Automatic Pulse Frequency Modulation Mode at Light Loads
- up to 93% Efficiency
- Available in a 6-Pin SOT-23-6L Package
- RoHS Compliant, 100%Pb & Halogen Free

Applications

- Battery-Powered Equipment
- Set-Top Boxed
- LCD Bais Supply
- DSL and Cable Modems and Routers
- Networking cards powered from PCI or PCI express slots





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Packages & Pin Assignments

| GS5802RF (SOT-23-6L) | | | |
|--|--|--|--|
| | NC V _{IN} EN 6 5 4 1 2 3 SW GND FB | | |
| Pin Name | Function | | |
| SW | Power Switch Output. SW is the drain of the internal MOSFET switch. Connect the power inductor and output rectifier to SW. SW can swing between GND and 28V. | | |
| GND | GND Ground Pin | | |
| FB Feedback Input. The FB voltage is 0.6V. Connect a resistor divider to FB. | | | |
| EN Regulator On/Off Control Input. A high input at EN turns on the converter, and a low input turns it off. When not used, connect EN to the input supply for automatic startup. | | | |
| V _{IN} | Input Supply Pin. Must be locally bypassed. | | |
| NC | NC No connected. | | |

Typical Application Circuit



Figure1. GS5802 Adjustable Output Voltage Regulator





Ordering Information



Marking Information



| Part Number | Package | GS P/N | Voltage Code | Date Code |
|-------------|-----------|--------|--------------|-----------|
| GS5802RF | SOT-23-6L | B6 | 28 | DC |

Absolute Maximum Ratings (Note 1)

| Symbol | Description | Value | Units |
|-------------------|--|------------|-------|
| V _{IN} | Input Supply Voltage | -0.3 to 26 | V |
| V _{EN} | EN Voltages | -0.3 to 26 | V |
| V _{SW} | SW Voltage | -0.3 to 30 | V |
| V _{FB} | FB Voltage | -0.3 to 6 | V |
| I _{PEAK} | Peak SW Sink and Source Current | 4 | A |
| PD | Power Dissipation | 0.6 | W |
| θ _{JA} | Thermal Resistance Junction to Ambient | 250 | °C/W |
| θ _{JC} | Thermal Resistance Junction to Case | 130 | °C/W |
| T _A | Operating Temperature Range | -40 to +85 | °C |
| TJ | Junction Temperature(Note 2) | 160 | °C |
| T _{STG} | Storage Temperature Range -65 to +150 | | °C |
| T _{LEAD} | Lead Temperature(Soldering,10s) 300 | | °C |
| ESD | HBM(Human Body Mode) | 2000 | V |
| E3D | MM(Machine Mode) | 200 | V |

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired. Note 2: T_J is calculated from the ambient temperature T_A and power dissipation P_D according to the following

formula: T_J = T_A + (P_D) x (θ_{JA}).
Note 3: 100% production test at 25°C. Specifications over the temperature range are guaranteed by design and characterization.



Electrical Characteristics

| $V_{IN}=V_{EN}=5V, T_A=25^{\circ}C,$ | unless otherwise noted. |
|--------------------------------------|-------------------------|
|--------------------------------------|-------------------------|

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Unit |
|-----------------------|-------------------------------------|------------------------------------|-------|-----|-------|------|
| V _{IN} | Input Voltage | - | 2.3 | - | 24 | V |
| | Under Voltage Lockout | - | - | - | 1.98 | V |
| V _{UVLO} | Under Voltage Lockout Hysteresis | - | - | 100 | - | mV |
| I _S | Current (Shutdown) | V _{EN} =0V | - | 0.1 | 1 | μA |
| la | Quiescent Current (PFM Mode) | V _{FB} =0.7V, NO switch | - | 100 | 200 | μA |
| ιQ | Quiescent Current (PWM Mode) | V_{FB} =0.5V, switch | - | 1.6 | 2.2 | mA |
| Fsw | Switching Frequency | - | - | 1.2 | - | MHz |
| D _(MAX) | Maximum Duty Cycle | V _{FB} =0V | 90 | - | - | % |
| V_{EH} | EN Input High Voltage | - | 1.5 | - | - | V |
| V _{EL} | EN Input Low Voltage | - | - | - | 0.4 | V |
| V_{FB} | FB Voltage | - | 0.588 | 0.6 | 0.612 | V |
| I _{FB} | FB Input Bias Current | V _{FB} =0.6V | -50 | -10 | | nA |
| R _{DS(ON)} | SW On Resistance (1) | - | - | 80 | 150 | mΩ |
| I _{SW} | SW Current Limit (1) | V _{IN} =5V,Duty cycle=50% | - | 4 | - | А |
| I _{sw_} Leak | SW Leakage | V _{SW} =20V | - | - | 1 | μA |
| T _{SD} | Thermal Shutdown | - | - | 155 | - | °C |

Note : (1) Guaranteed by design, not tested.



Typical Performance Characteristics Efficiency Curve



Efficiency Curve Vin=13V; Vout=18V









Load regualation







Efficiency VS V_{IN}



GS5802

Applications Information

Operation

The GS5802 uses a fixed frequency, peak current mode boost regulator architecture to regulate voltage at the feedback pin. The operation of the GS5802 can be understood by referring to the block diagram. At the start of each oscillator cycle the MOSFET is turned on through the control circuitry. To prevent sub-harmonic oscillations at duty cycles greater than 50 percent, a stabilizing ramp is added to the output of the current sense amplifier and the result is fed into the negative input of the PWM comparator. When this voltage equals. The output voltage of the error amplifier the power MOSFET is turned off. The voltage at the output of the error amplifier is an amplified version of the difference between the 0.6V bandgap reference voltage and the feedback voltage. In this way the peak current level keeps the output in regulation. If the feedback voltage starts to drop, the output of the error amplifier increases. These results in more current to flow through the power MOSFET, thus increasing the power delivered to the output.

The GS5802 has internal soft start to limit the amount of input current at startup and to also limit the amount of overshoot on the output.

Setting the Output Voltage

The internal reference V_{REF} is 0.6V (Typical). The output voltage is divided by a resistor divider, R1 and R2 to the FB pin. The output voltage is given by:

Inductor Selection

The recommended values of inductor are 4.7 to 22µH. Small size and better efficiency are the major concerns for portable device, such as GS5802 used for mobile phone. The inductor should have low core loss at 1.2MHz and low DCR for better efficiency. To avoid inductor saturation current rating should be considered.

Capacitor Selection

Input and output ceramic capacitors of 22µF are recommended for GS5802 applications. For better voltage filtering, ceramic capacitors with low ESR are recommended. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

Diode Selection

Schottky diode is a good choice for GS5802 because of its low forward voltage drop and fast reverses recovery. Using Schottky diode can get better efficiency. The high speed rectification is also a good characteristic of Schottky diode for high switching frequency. Current rating of the diode must meet the root mean square of the peak current and output average current multiplication as following:

I_D(RMS) ≈ √ I_{OUT}XI_{PEAK}

The diode's reverse breakdown voltage should be larger than the output voltage.

Layout Consideration

For best performance of the GS5802, the following guidelines must be strictly followed.

- 1. Input and Output capacitors should be placed close to the IC and connected to ground plane to reduce noise coupling.
- 2. The GND should be connected to a strong ground plane for heat sinking and noise protection.
- 3. Keep the main current traces as possible as short and wide.
- 4. SW node of DC-DC converter is with high frequency voltage swing. It should be kept at a small area.
- 5. Place the feedback components as close as possible to the IC and keep away from the noisy devices.





Package Dimension



SOT-23-6L PLASTIC PACKAGE

| Dimensions | | | | | |
|------------|-------------|-------|------------|-------|--|
| SVMBOL | Millimeters | | Inches | | |
| STIVIDOL | MIN | MAX | MIN | MAX | |
| Α | - | 1.10 | - | .043 | |
| A1 | 0.00 | 0.10 | 0 | .004 | |
| A2 | 0.70 | 1.00 | .028 | .039 | |
| b | 0.30 | 0.50 | .012 .020 | | |
| С | 0.08 | 0.20 | .003 .008 | | |
| D | 2.90 (TYP) | | .114 (TYP) | | |
| E | 2.80 (TYP) | | .110 (TYP) | | |
| E1 | 1.60 (TYP) | | .063 (TYP) | | |
| e | 0.95 (TYP) | | .037 (TYP) | | |
| e1 | 1.90 | (TYP) | .075 (TYP) | | |
| L | 0.30 | 0.60 | .014 .022 | | |
| L1 | 0.60 (TYP) | | .024 (TYP) | | |
| R | 0.10 | - | .004 - | | |
| R1 | 0.10 | 0.25 | .004 .010 | | |
| G | 0.25 | (TYP) | .010 | (TYP) | |
| θ | 0° | 8° | 0° | 8° | |



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